

Octal D-Type Latch with 3-STATE Outputs

74VHC573

General Description

The VHC573 is an advanced high speed CMOS octal latch with 3–STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8–bit D–type latch is controlled by a latch enable input (LE) and an Output Enable input (\overline{OE}) . When the \overline{OE} input is HIGH, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0 V to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed: $t_{PD} = 5.0 \text{ ns}$ (Typ) at $V_{CC} = 5 \text{ V}$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min)
- Power Down Protection is Provided on All Inputs
- Low Noise: $V_{OLP} = 0.6 \text{ V (Typ)}$
- Low Power Dissipation: $I_{CC} = 4 \mu A \text{ (Max) } @ T_A = 25 \text{ °C}$
- Pin and Function Compatible with 74HC573
- This is a Pb-Free Device

Logic Symbol

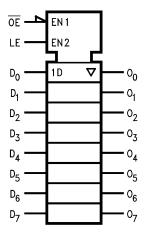


Figure 1. Logic Symbol



TSSOP20, 4.4x6.5 CASE 948AQ

MARKING DIAGRAM

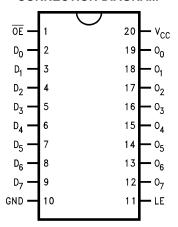


XXXXXX = Specific Device Code A = Assembly Location

L = Wafer Lot Y = Year W = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

CONNECTION DIAGRAM



PIN DESCRIPTION

l	Pin Names	Description	
	D ₀ –D ₇	Data Inputs	
LE Latch Enable Input			
	ŌĒ	3-STATE Output Enable Input	
	O ₀ –O ₇	3-STATE Outputs	

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

TRUTH TABLE

	Outputs		
OE	LE	D	On
L	Н	Н	Н
L	Н	L	L
L	L	Х	O ₀
Н	Х	Х	Z

H = HIGH Voltage Level

L = LOW Voltage Level

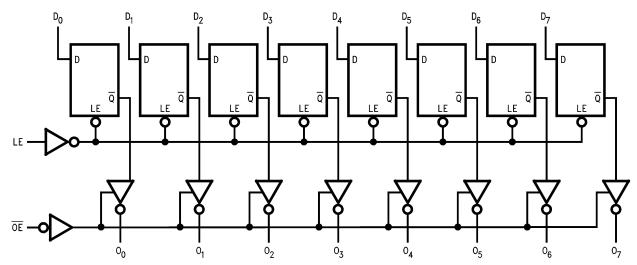
X = Immaterial

Z = High Impedance

Functional Description

The VHC573 contains eight D–type latches with 3–STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the Dn inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs, a setup time preceding the HIGH–to–LOW transition of LE. The 3–STATE buffers are controlled by the Output Enable $\overline{(OE)}$ input. When \overline{OE} is LOW, the buffers are enabled. When \overline{OE} is HIGH the buffers are in the high impedance mode, but, this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 2. Logic Diagram

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MAXIMUM RATINGS

Symbol	Par	ameter	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +6.5	V	
V _{IN}	DC Input Voltage	-0.5 to +6.5	V	
V _{OUT}	DC Output Voltage		-0.5 to V _{CC} + 0.5	V
I _{IN}	DC Input Current		±20	mA
I _{OUT}	DC Output Current		±25	mA
I _{CC}	DC Supply Current, V _{CC} and GND Pins	3	±75	mA
I _{IK}	Input Clamp Current	-20	mA	
I _{OK}	Output Clamp Current	±20	mA	
T _{STG}	Storage Temperature Range	-65 to +150	°C	
TL	Lead Temperature, 1 mm from Case for	10 Seconds	260	°C
TJ	Junction Temperature under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 2)		150	°C/W
P _D	Power Dissipation in Still Air at 25 °C		833	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.573 in	
V _{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model	2000	V
		Charged Device Model	N/A	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Applicable to devices with outputs that may be tri-stated.
- 2. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
- 3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	Para	Min	Max	Unit	
V _{CC}	DC Supply Voltage	2.0	5.5	V	
V _{IN}	DC Input Voltage (Note 4)	0	5.5	V	
V _{OUT}	DC Output Voltage (Note 4)	0	V _{CC}	V	
T _A	Operating Temperature	-40	+85	°C	
t _r , t _f	Input Rise or Fall Rate	V _{CC} = 3.0 V to 3.6 V	0	100	ns/V
		V _{CC} = 4.5 V to 5.5 V	0	20	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

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DC ELECTRICAL CHARACTERISTICS

						T _A = 25 °C	;	T _A = -40 °C	C to +85 °C	
Symbol	Parameter	Con	ditions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
V_{IH}	HIGH Level			2.0	1.50	-	_	1.50	_	V
	Input Voltage			3.0-5.5	0.7 x V _{CC}	_	-	0.7 x V _{CC}	-	
V _{IL}	LOW Level			2.0	-	_	0.50	-	0.50	V
	Input Voltage			3.0-5.5	-	_	0.3 x V _{CC}	-	0.3 x V _{CC}	
V _{OH}	HIGH Level	$V_{IN} = V_{IH}$	$I_{OH} = -50 \mu A$	2.0	1.9	2.0	-	1.9	_	V
	Output Voltage	or V _{IL}		3.0	2.9	3.0	-	2.9	-	
				4.5	4.4	4.5	-	4.4	-	
			$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	-	2.48	-	
			$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	-	3.80	_	
V _{OL}	LOW Level	$V_{IN} = V_{IH}$	I _{OL} = 50 μA	2.0	-	0.0	0.1	-	0.1	V
	Output Voltage or V _{IL}	or V _{IL}		3.0	-	0.0	0.1	-	0.1	
				4.5	-	0.0	0.1	-	0.1	
			$I_{OL} = 4 \text{ mA}$	3.0	-	_	0.36	-	0.44	
			$I_{OL} = 8 \text{ mA}$	4.5	-	_	0.36	-	0.44	
I _{OZ}	3–STATE Output Off–State Current	$V_{IN} = V_{IH} c$ $V_{OUT} = V_{C}$		5.5	-	-	±0.25	_	±2.5	μΑ
I _{IN}	Input Leakage Current	V _{IN} = 5.5 \	or GND	0–5.5	-	-	±0.1	_	±1.0	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$	or GND	5.5	-	ı	4.0	_	40.0	μΑ

NOISE CHARACTERISTICS

				T _A = 25 °C		
Symbol	Parameter	Conditions	V _{CC} (V)	Тур	Limits	Unit
V _{OLP} (Note 5)	Quiet Output Maximum Dynamic V _{OL}	C _L = 50 pF	5.0	0.9	1.2	V
V _{OLV} (Note 5)	Quiet Output Minimum Dynamic V _{OL}	C _L = 50 pF	5.0	-0.8	-1.0	V
V _{IHD} (Note 5)	Minimum HIGH Level Dynamic Input Voltage	C _L = 50 pF	5.0	-	3.5	V
V _{ILD} (Note 5)	Maximum LOW Level Dynamic Input Voltage	C _L = 50 pF	5.0	-	1.5	V

^{5.} Parameter guaranteed by design.

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AC ELECTRICAL CHARACTERISTICS

						T _A = 25 °C		T _A = -40 °C	C to +85 °C				
Symbol	Parameter	Con	ditions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit			
t _{PLH} , t _{PHL}	Propagation		C _L = 15 pF	3.3 ±0.3	-	7.6	11.9	1.0	14.0	ns			
	Delay Time (LE to O _n)		C _L = 50 pF		-	10.1	15.4	1.0	17.5				
			C _L = 15 pF	5.0 ±0.5	-	5.0	7.7	1.0	9.0	ns			
			C _L = 50 pF		_	6.5	9.7	1.0	11.0				
t _{PLH} , t _{PHL}	Propagation		C _L = 15 pF	3.3 ±0.3	_	7.0	11.0	1.0	13.0	ns			
	Delay Time (D-O _n)		C _L = 50 pF	1	-	9.5	14.5	1.0	16.5				
			C _L = 15 pF	5.0 ±0.5	-	4.5	6.8	1.0	8.0				
			C _L = 50 pF	1	-	6.0	8.8	1.0	10.0				
t _{PZL} , t _{PZH}	t _{PZH} 3–STATE Output Enable Time	$R_L = 1 \text{ k}\Omega$	C _L = 15 pF	3.3 ±0.3	-	7.3	11.5	1.0	13.5	ns			
				C _L = 50 pF		-	9.8	15.0	1.0	17.0			
							C _L = 15 pF	5.0 ±0.5	-	5.2	7.7	1.0	9.0
			C _L = 50 pF	1	-	6.7	9.7	1.0	11.0				
t _{PLZ} , t _{PHZ}	3-STATE	3–STATE Output Disable	$R_L = 1 \text{ k}\Omega$	$C_L = 50 \text{ pF}$	3.3 ±0.3	-	10.7	14.5	1.0	16.5	ns		
	Time		C _L = 50 pF	5.0 ±0.5	-	6.7	9.7	1.0	11.0				
toslh,	Output to	(Note 6)	C _L = 50 pF	3.3 ±0.3	_	-	1.5	-	1.5	ns			
toshl	Output Skew		C _L = 50 pF	5.0 ±0.5	_	-	1.0	-	1.0				
C _{IN}	Input Capacitance	V _{CC} = Open			-	4	10	-	10	pF			
C _{OUT}	Output Capacitance	V _{CC} = 5.0 V			-	6	_	-	-	pF			
C _{PD}	Power Dissipation Capacitance	(Note 7)			-	29	-	-	-	pF			

AC OPERATING REQUIREMENTS

				T _A = 25 °C		T _A = -40 °C	C to +85 °C	
Symbol	Parameter	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
t _W (H),	Minimum Pulse Width (LE)	3.3 ±0.3	5.0	-	-	5.0	_	ns
$t_W(L)$		5.0 ±0.5	5.0	_	-	5.0	-	
t _S	Minimum Setup Time	3.3 ±0.3	3.5	-	_	3.5	_	ns
		5.0 ±0.5	3.5	-	-	3.5	_	
t _H	Minimum Hold Time	3.3 ±0.3	1.5	-	_	1.5	_	ns
		5.0 ±0.5	1.5	_	_	1.5	_	

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
74VHC573MTC	VHC 573	TSSOP20 (Pb-Free)	75 Units / Tube
74VHC573MTCX	VHC 573	TSSOP20 (Pb-Free)	2500 Units / Tape & Reel

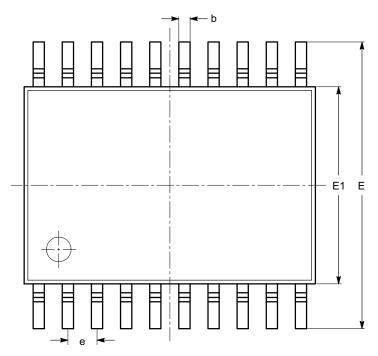
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{6.} Parameter guaranteed by design. $t_{OSLH} = |t_{PLH \; max} - t_{PLH \; min}|$; $t_{OSHL} = |t_{PHL \; max} - t_{PHL \; min}|$ 7. t_{CPD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $t_{CC}(t_{CPL}) = t_{CPD} \cdot t_{CC} \cdot t_{IN} + t_{CC} \cdot$



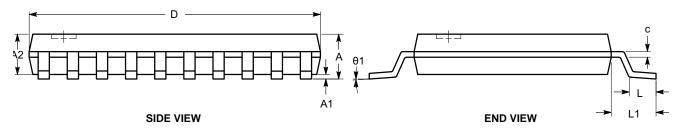
TSSOP20, 4.4x6.5 CASE 948AQ ISSUE A

DATE 19 MAR 2009



SYMBOL	MIN	NOM	MAX
А			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
С	0.09		0.20
D	6.40	6.50	6.60
Е	6.30	6.40	6.50
E1	4.30	4.40	4.50
е		0.65 BSC	
L	0.45	0.60	0.75
L1		1.00 REF	
θ	0°		8°

TOP VIEW



Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

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